

50 .. 600 A

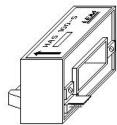
# **Current Transducers HAS 50 to 600-S**

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e electronic measurement of currents: DC, AC, pulsed, mixed, galvanic isolation between the primary circuit (high power) and	$V_{OUT}$ =	± 4 V	
condary circuit (electronic circuit).		10 <b>31</b>	



# **Electrical data**

Primary nomir r.m.s. current $I_{_{PN}}(A)$	•	Туре		
50	± 150	HAS 50-S		
100	± 300	HAS 100-S		
200	± 600	HAS 200-S		
300	± 900	HAS 300-S		
400	± 900	HAS 400-S		
500	± 900	HAS 500-S		
600	± 900	HAS 600-S		
<b>V</b> <sub>c</sub>	Supply voltage (± 5 %)		± 15	V
I,	Current consumption		± 15	mΑ
I <sub>C</sub> I <sub>OC</sub> V	Overload capacity		30,000	At
<b>V</b> d	R.m.s. voltage for AC isolat	tion test, 50/60 Hz, 1 mn	3	kV
<b>V</b> <sub>b</sub>	R.m.s. rated voltage, safe separation		500 <sup>1)</sup>	V
<b>R</b> <sub>IS</sub>	Isolation resistance @ 500	VDC	> 1000	$M\Omega$
<b>V</b> <sub>OUT</sub>	Output voltage $@ \pm I_{PN}$ , $R_L =$	$= 10 \text{ k}\Omega, \mathbf{T}_A = 25^{\circ}\text{C}$	±	4V ±

<b>v</b> <sub>C</sub>	Supply voltage (± 5 %)		± 13	V
I <sub>C</sub>	Current consumption		± 15	mΑ
I <sub>oc</sub>	Overload capacity		30,000	At
<b>V</b> <sub>d</sub>	R.m.s. voltage for AC isolation test, 50/60 Hz	z, 1 mn	3	kV
<b>V</b> <sub>b</sub>	R.m.s. rated voltage, safe separation		500 <sup>1)</sup>	V
R <sub>IS</sub>	Isolation resistance @ 500 VDC		> 1000	$M\Omega$
V <sub>OUT</sub>	Output voltage @ $\pm I_{PN}$ , $R_1 = 10 \text{ k}\Omega$ , $T_A = 25^{\circ}\text{C}$			± 4V ±
40 mV				
$\mathbf{R}_{OUT}$	Output internal resistance	approx.	100	Ω
R <sub>i</sub>	Load resistance		> 1	$k\Omega$
=				

# Accuracy - Dynamic performance data

X	Accuracy @ $I_{PN}$ , $T_{A} = 25^{\circ}C$	(without offset)	< ± 1	%
<b>e</b>	Linearity 2) (0 ± Î <sub>PN</sub> )		< ± 1	% of I <sub>PN</sub>
<b>V</b> OE	Electrical offset voltage, $T_{\Delta} = 25^{\circ}\text{C}$		$< \pm 20$	mΫ
V <sub>OH</sub>	Hysteresis offset voltage @	$\mathfrak{D}   \mathbf{I}_{p} = 0;$		
<b>5</b>	after an excursion of 1 x Iph	I	$< \pm 20$	mV
$\mathbf{V}_{OT}$	Thermal drift of <b>V</b> <sub>OF</sub>	HAS 50-S	$< \pm 2$	mV/K
0.	52	HAS 100 to HAS 600-S	< ± 1	mV/K
TC <b>C</b> <sub>G</sub>	Thermal drift of the gain (%	6 of reading)	$< \pm 0.1$	%/K
t, °	Response time @ 90% of	I <sub>p</sub>	< 3	μs
di/dt	di/dt accurately followed		> 50	A/μs
f			DC 50	) kHz

## **General data**

T <sub>A</sub>	Ambient operating temperature Ambient storage temperature		- 10 + 80 - 25 + 80	_
m	Mass Standards 4)	approx.	60 EN 50178	g

#### **Features**

- Hall effect measuring principle
- Galvanic isolation between primary and secondary circuit
- Isolation voltage 3000 V~
- Low power consumption
- Extended measuring range (3 x I<sub>DN</sub>)
- Insulated plastic case made of polycarbonate PBT recognized according to UL 94-V0

## **Advantages**

- Easy mounting
- Small size and space saving
- Only one design for wide current ratings range
- High immunity to external interference.

## **Applications**

- AC variable speed drives
- Static converters for DC motor drives
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications.

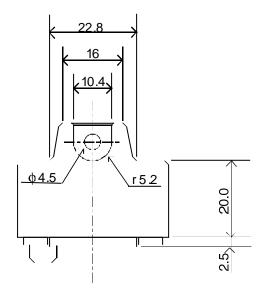
Notes: 1) Pollution class 2, overvoltage category III.

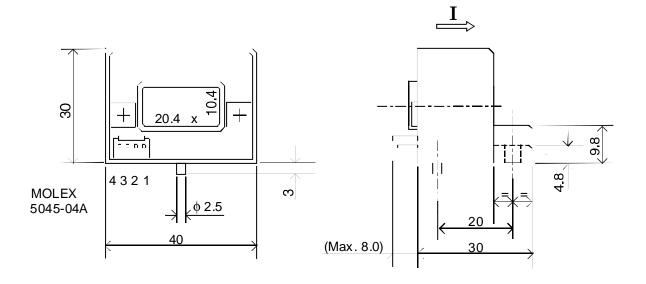
- <sup>2)</sup> Linearity data exclude the electrical offset.
- <sup>3)</sup> Please refer to derating curves in the technical file to avoid excessive core heating at high frequency.
- 4) Please consult characterisation report for more technical details and application advice.

981007/4



# HAS 50 to 600-S Dimensions (in mm)





# PINS ARRANGEMENT

$$1 = +15V$$

$$4 = 0V$$